## O.staxx A109





Q.staxx brings the high precision and performance of Q.bloxx into robust, pallet mount, cast aluminum (IP65) Harting enclosures - the ideal solution for extremely harsh test cell environments. Q.staxx modules are interchangeable and can be mounted directly onto pallet systems since the passive backplane does not require fans, filters or environmental conditioning further reducing setup time as sensors can remain fixed to an engine while the pallet transitions between test cells and measurement requirements.

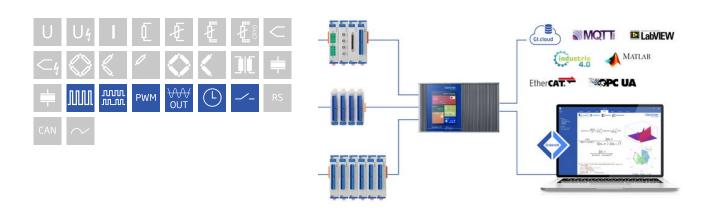
- IP 65 (Dust Protected and water jet tested)
- Robust design for Pallet Systems

- Connectable to any Controller, e. g. Q.gate or Q.pac
- Power supply 10 ... 30 VDC



#### **Key Features**

- 4 Analog output channels voltage (±10 VDC) or current (0 - 20 mA), configurable per channel
- DAC-resolution 16 bit 100 kHz each channel
- Outputs freely scalable
- 4 digital inputs and outputs configurable as 2 counter, 2 frequency, or 2 PWM inputs, 4 frequency out, 4 PWM output or 4 state out
- Frequency measurement Frequency measurement up to 1 MHz, direction detection
- Counter Forward-backward counter, quadrature counter with reference position recognition (reset/enable), up to 1 MHz
- PWM input Measurement of duty cycle and frequency
- 3-Way galvanic isolation Channel to channel, channel to power supply, and bank

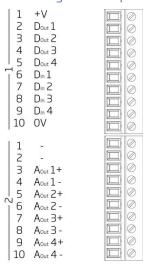


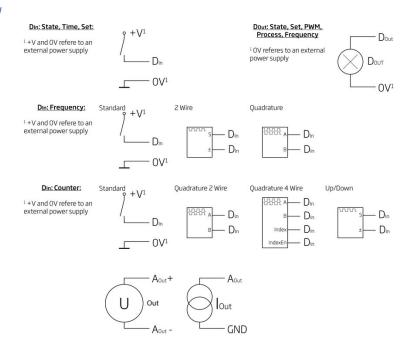


## Analog Output Module with Digital I/Os

#### **Technical Data**

### Terminal assignment 10pole screw





### Analog Output

Channels	4
Output type	voltage or current, configurable per channel
lsolation voltage	500 VDC channel to channel to power supply channel to bus <sup>1</sup>

<sup>1</sup> noise pulses up to 1000 VDC, continuous up to 250 VDC

### Output Mode Voltage

Output voltage	±10 VDC	
Allowable load resistance	>2 kΩ	
Long-term drift	<1 mV / 24 hrs	<2.5 mV / 8000 hrs
Temperature influence	<2 mV / 10 K Offset drift	< 0.05 % / 10 K Gain drift
Noise voltage	<10 mV at 1000 Hz	<2 mV at 10 Hz

### **Current Output**

Output current	0 - 20 mA	
Load burden	<400 Ω	
burden influence	<0.1 μΑ/Ω	
Long-term stability	<2 μA / 24 hrs	<5 μA / 8000 hrs
Temperature drift	<4 µA / 10 K Offset drift	< 0.05 % / 10 K Gain drift
Noise current	<20 μA at 1000 Hz	< 4 μA at 10 Hz



## Analog Output Module with Digital I/Os

## Digital Input

Channels	4
Logic levels	TTL or 24 VDC according to IEC 61131-2, Type 1
TTL logic voltage	< 0.8 VDC (Low) > 3 VDC (High)
24 VDC logic voltage	-3 to 5 VDC (Low) 11 to 30 VDC (High)
Input type	PNP (current sinking)
Input voltage	30 VDC max.
Input current	2 mA max.
Isolation voltage	500 VDC, group to group, group to power supply, channel to bus <sup>1</sup>

 $<sup>^{\</sup>rm 1}\,$  noise pulses up to 1000 VDC, continuous up to 250 VDC

### Digital Input Modes

Status	
Response time	10 µs
Frequency measurement	
Method	Chronos method (optimized by a combination of time measurement and pulse counting), detection of rotational direction (0 deg. / 90 deg.)
Frequency range	0.1 Hz to 1 MHz
Time base	0.001 s to 1 s
Internal reference frequency	48 MHz
Accuracy	0.01% at timebase > 1ms
Resolution	21 ns
Pulse counting	
Accuracy	0.01% at timebase > 1ms
Resolution	21 ns
Counter frequency	1 MHz
Mode(s) of operation	<ul> <li>Forward and reverse counting (additional input for direction of counting)</li> <li>Quadrature counter (additional input for detection of rotational direction)</li> <li>Quadrature counter with zero reference and reset/enable (two additional inputs)</li> </ul>
Pulse-width measurement	
Input frequency	0.1 Hz to 1 MHz
Accuracy	0.01% at timebase > 1ms
Resolution	21 ns

## Digital Output

Channels	4
Contact	open drain p-channel MOSFET
Output voltage	12 to 30 VDC (external supply required)
Load capacity	30 VDC / 500 mA (ohmic load)
Isolation voltage	500 VDC, group to group, group to power supply, channel to bus <sup>1</sup>

 $<sup>^{\,1}</sup>$  noise pulses up to 1000 VDC, continuous up to 250 VDC



## Analog Output Module with Digital I/Os

## Digital Output Modes

Status			
Response time	10 μs (>0.5 A)	100 μs (>0.1 A)	1000 μs (<0.1 A)
Frequency output		-	
Frequency range	0.1 Hz to 1 kHz / 10 kHz (depending on load capacity)		
Accuracy	0.1%		
Resolution	1 µs		
PWM output			
Frequency range	0.1 Hz to 1 kHz / 10 kHz (depending on load capacity)		
Accuracy	0.1 %		
Resolution	1 µs		

## Digital to Analog Conversion

Resolution	16-bit
Update rate	100 kHz per channel
Settling time	З µѕ

### Communication Interface

Protocols	proprietary Localbus (115200 bps to 24 Mbps, latency <100 ns) ASCII (19200 bps to 115200 bps) Modbus RTU Profibus-DP (19200 bps to 12 Mbps) (special Firmware required)
Data format	8E1
Electrical standard	ANSI/TIA/EIA-485-A, 2-wire

### Input Power

Input voltage	10 to 30 VDC, overvoltage and overcurrent protection
Power consumption	2 W (approx.)
Input voltage influence	<0.001 % / V

## **Environmental Specifications**

Electromagnetic compatibility	according to IEC 61000-4 and EN 55011
Operating temperature	-20°C to +60°C
Storage temperature	-40°C to +85°C
Relative humidity	5 - 95 % at 50°C (non-condensing)

#### Remarks

Are subject to a warm-up period of at least 45 minutes

in a controlled electromagnetic environment  $^{\scriptsize 1}$ 

Specifications subject to change without notice

 $<sup>^{\</sup>rm 1}$  according to EN 61326 2006: appendix B



## Analog Output Module with Digital I/Os

### Mechanical information

Material	Aluminum
Measurements (W x H x D)	45 x 120 x 113 mm
Weight	approx. 700 g

## Ordering Information

Article number	704023

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